

**INFORMATION DISCLOSURE CITATION**  
*(Use several sheets if necessary)*

(Use several sheets if necessary)

**Docket Number (Opt)**

TL-2 10.1

**Application Number:**

10/054 957

**Applicant(s)**

Theodore W. Houston et al.

**Filing Date**

10/25/02  
Herewith

### Group Art Unit

2822

## U.S. PATENT DOCUMENTS

J1046 U.S. PRO  
10/05/4957  
01/25/02

## FOREIGN PATENT DOCUMENTS

**OTHER DOCUMENTS** *(Including Author, Title, Date, Pertinent Pages, Etc.)*

G.G. Shahidi et al. "Indium Channel Implant for Improved Short-Channel Behavior of Submicrometer NMOSFETs", IEEE 1993, pp 409-411

TMT

T. Thomas

**DATE CONSIDERED**

03-09-03

**EXAMINER:** Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.